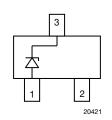


# Vishay Semiconductors

# **Single-Line ESD-Protection Diode in SOT-23**





### **MARKING** (example only)



YYY = type code (see table below) X = date code

### **FEATURES**

- Single-line ESD-protection device
- ESD-immunity acc. IEC 61000-4-2
   ± 30 kV contact discharge
  - ± 30 kV air discharge
- Space saving SOT-23 package
- · AEC-Q101 qualified
- e3 Sn
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC





COMPLIANT

GREEN

(5-2008)\*\*

Available

ORDERING INFORMATION						
DEVICE NAME	ENVIRONMENTAL STATUS	ORDERING CODE	TAPED UNITS PER REEL (8 mm TAPE ON 7" REEL)	MINIMUM ORDER QUANTITY		
GSOT05L-V	Standard	GSOT05L-V-GS08	3000	15 000		
	Green	GSOT05L-V-G-08	3000			

PACKAGE DATA							
DEVICE NAME	PACKAGE NAME	TYPE CODE	ENVIRONMENTAL STATUS	WEIGHT	MOLDING COMPOUND FLAMMABILITY RATING	MOISTURE SENSITIVITY LEVEL	SOLDERING CONDITIONS
GSOT05L-V	SOT-23	05L	Standard	8.8 mg	UL 94 V-0	MSL level 1	260 °C/10 s at terminals
G30103L-V	301-23	5LG	Green	8.1 mg	OL 94 V-0	(according J-STD-020)	200 O/10's at terrillials

ABSOLUTE MAXIMUM RATINGS GSOT05L-V					
PARAMETER	TEST CONDITIONS SYMBOL		VALUE	UNIT	
Peak pulse current	Pin 3 to 1 acc. IEC 61000-4-5, 8/20 μs/single shot	I <sub>PPM</sub>	13	Α	
Peak pulse power	Pin 3 to 1 acc. IEC 61000-4-5, 8/20 μs/single shot	P <sub>PP</sub>	156	W	
FCD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses	W	± 30	kV	
ESD immunity	Air discharge acc. IEC 61000-4-2; 10 pulses	$V_{ESD}$	± 30	kV	
Operating temperature	Junction temperature	TJ	- 40 to + 150	°C	
Storage temperature		T <sub>STG</sub>	- 55 to + 150	°C	

<sup>\*\*</sup> Please see document "Vishay Material Category Policy": <a href="www.vishay.com/doc?99902">www.vishay.com/doc?99902</a>

# Vishay Semiconductors Single-Line ESD-Protection Diode in SOT-23



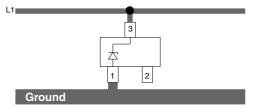
### **BIAs-MODE** (bidirectional asymmetrical protection mode)

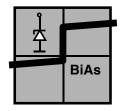
With the GSOT05L-V one signal- or data-lines (L1) can be protected against voltage transients. With pin 1 connected to ground and pin 3 connected to a signal- or data-line which has to be protected. As long as the voltage level on the data- or signal-line is between 0 V (ground level) and the specified maximum reverse working voltage (V<sub>RWM</sub>) the protection diode between data line and ground offers a high isolation to the ground line. The protection device behaves like an open switch.

As soon as any positive transient voltage signal exceeds the break through voltage level of the protection diode, the diode becomes conductive and shorts the transient current to ground. Now the protection device behaves like a closed switch. The clamping voltage  $(V_C)$  is defined by the breakthrough voltage  $(V_{BR})$  level plus the voltage drop at the series impedance (resistance and inductance) of the protection device.

Any negative transient signal will be clamped accordingly. The negative transient current is flowing in the forward direction of the protection diode. The low forward voltage  $(V_F)$  clamps the negative transient close to the ground level.

Due to the different clamping levels in forward and reverse direction the GSOT05L-V clamping behaviour is bidirectional and asymmetrical (BiAs).





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ELECTRICAL CHARACTERISTICS GSOT05L-V								
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT		
Protection paths	Number of lines which can be protected	N <sub>lines</sub>	-	-	1	lines		
Reverse stand off voltage	at I <sub>R</sub> = 1 μA	$V_{RWM}$	5.5	6.1	7	V		
Reverse current	at V <sub>R</sub> = 5.5 V	I <sub>R</sub>	-	=	1	μΑ		
Reverse breakdown voltage	at I <sub>R</sub> = 1 mA	$V_{BR}$	6	6.75	-	V		
Reverse clamping voltage	at I <sub>PP</sub> = 1 A	V <sub>C</sub>	-	6.9	9	V		
neverse clamping voltage	at $I_{PP} = I_{PPM} = 13 \text{ A}$	VC.	-	10	1 7 1 -	V		
Forward clamping voltage	at I <sub>PP</sub> = 1 A	at I <sub>PP</sub> = 1 A		1	1.3	V		
	at $I_{PP} = I_{PPM} = 13 \text{ A}$	│ VF	-	2.6	3	V		
Capacitance	at $V_R = 0 V$ ; $f = 1 MHz$	- C <sub>D</sub>	-	100	120	pF		
	at $V_R = 2.5 \text{ V}$ ; $f = 1 \text{ MHz}$	$\rceil$ $\overset{C_D}{}$ $[$	-	60	-	pF		

#### Note

#### **TYPICAL CHARACTERISTICS** (T<sub>amb</sub> = 25 °C, unless otherwise specified)

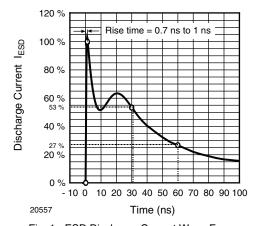


Fig. 1 - ESD Discharge Current Wave Form acc. IEC 61000-4-2 (330  $\Omega/150$  pF)

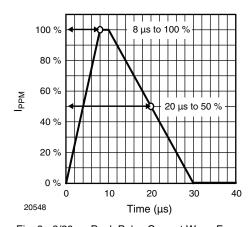


Fig. 2 - 8/20 μs Peak Pulse Current Wave Form acc. IEC 61000-4-5

Ratings at 25 °C, ambient temperature unless otherwise specified. BiAs mode (between pin 3 to 1).



# Single-Line ESD-Protection Diode in Vishay Semiconductors SOT-23

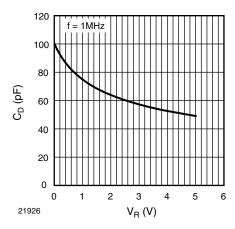


Fig. 3 - Typical Capacitance  $C_D$  vs. Reverse Voltage  $V_R$ 

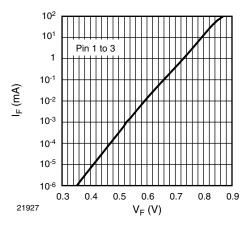


Fig. 4 - Typical Forward Current I<sub>F</sub> vs. Forward Voltage V<sub>F</sub>

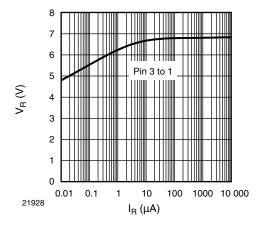


Fig. 5 - Typical Reverse Voltage V<sub>R</sub> vs. Reverse Current I<sub>R</sub>

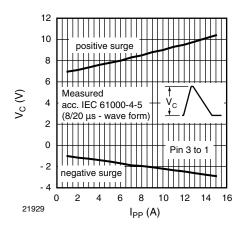


Fig. 6 - Typical Peak Clamping Voltage  $V_C$  vs. Peak Pulse Current  $I_{PP}$ 

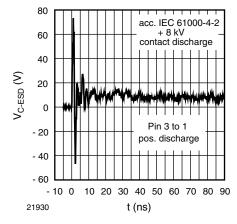


Fig. 7 - Typical Clamping Performance at + 8 kV Contact Discharge (acc. IEC 61000-4-2)

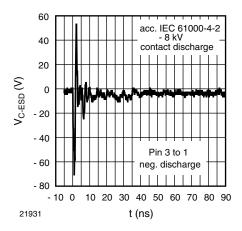


Fig. 8 - Typical Clamping Performance at - 8 kV Contact Discharge (acc. IEC 61000-4-2)

# Vishay Semiconductors Single-Line ESD-Protection Diode in SOT-23



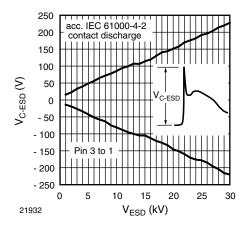
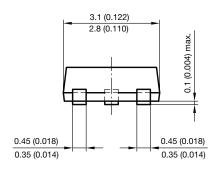
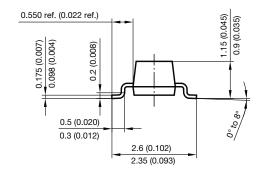
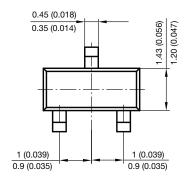


Fig. 9 - Typical Peak Clamping Voltage at ESD Contact Discharge (acc. IEC 61000-4-2)

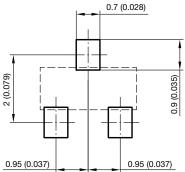
## PACKAGE DIMENSIONS in millimeters (inches): SOT-23







Foot print recommendation:



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